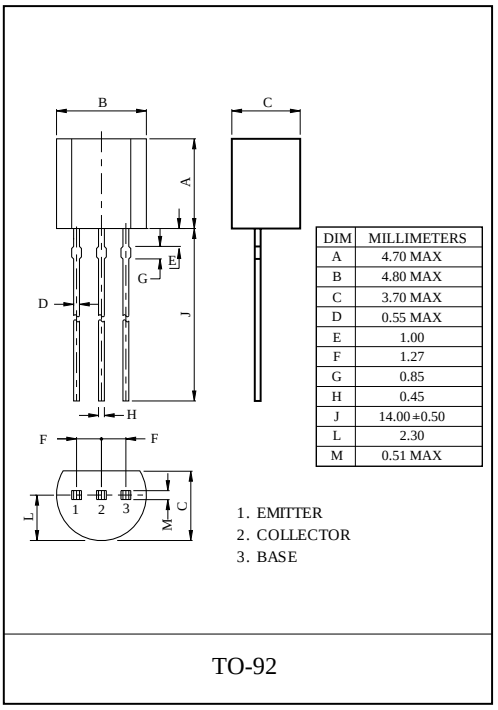
TRANSISTOR (NPN)

Low $V_{CE(sat)}$ Transistor(Strobe flash)

FEATURES

- Low $V_{CE(sat)}$.$V_{CE(sat)}$ = 0.25V (Typ.)(I_C/I_B= 4A / 0.1A)
- Excellent Dc current gain characteristics



DIM	MILLIMETERS
A	4.70 MAX
B	4.80 MAX
C	3.70 MAX
D	0.55 MAX
E	1.00
F	1.27
G	0.85
H	0.45
J	14.00 ±0.50
L	2.30
M	0.51 MAX

TO-92

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	20	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current -Continuous	5	A
P_C	Collector Power Dissipation	0.625	W
T_j	Junction Temperature	150	℃
T_{stg}	Storage Temperature	-55-150	℃

ELECTRICAL CHARACTERISTICS (T_a=25℃ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C=50μA,I_E=0	50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I_C=1mA,I_B=0	20			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E=50μA,I_C=0	6			V
Collector cut-off current	I_{CBO}	V_{CB}=40V,I_E=0			0.5	μA
Emitter cut-off current	I_{EBO}	V_{EB}=5V,I_C=0			0.5	μA
DC current gain	h_{FE}	V_{CE}=2V,I_C=0.5A	120		390	
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C=4A,I_B=100mA			1	V
Transition frequency	f_T	V_{CE}=6V,I_C=50mA,f=100MHz		150		MHz
Collector output capacitance	C_{ob}	V_{CB}=20V,I_E=0,f=1MHz		30		pF

CLASSIFICATION OF h_{FE}

Rank	Q	R
Range	120-270	180-390

● Electrical characteristic curves

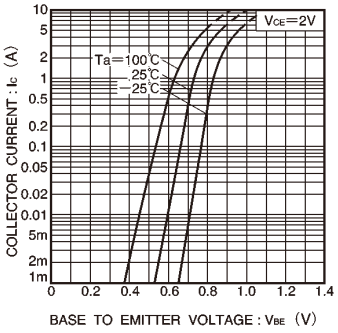


Fig.1 Grounded emitter propagation characteristics

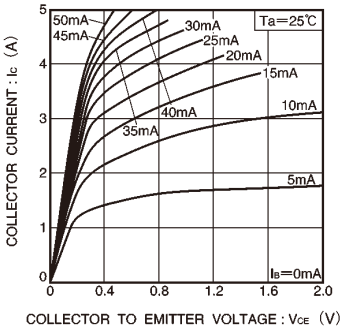


Fig.2 Grounded emitter output characteristics

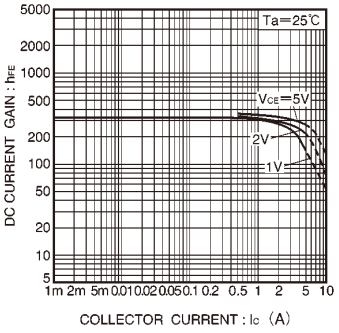


Fig.3 DC current gain vs. collector current (Ⅰ)

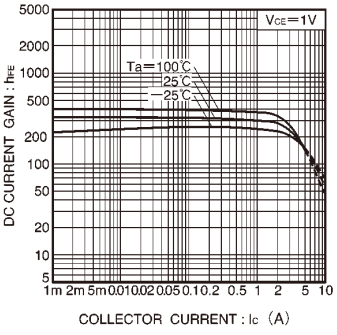


Fig.4 DC current gain vs. collector current (Ⅱ)

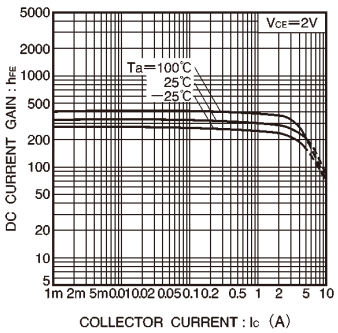


Fig.5 DC current gain vs. collector current (Ⅲ)

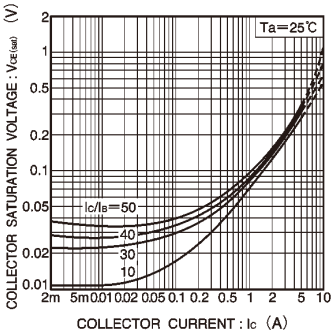


Fig.6 Collector-emitter saturation voltage vs. collector current (Ⅰ)

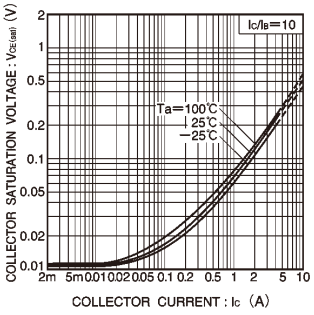


Fig.7 Collector-emitter saturation voltage vs. collector current (Ⅱ)

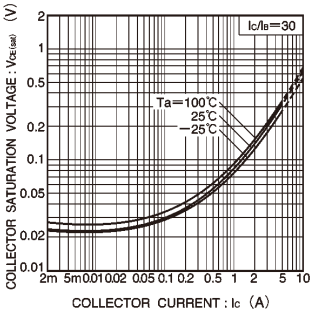


Fig.8 Collector-emitter saturation voltage vs. collector current (Ⅲ)

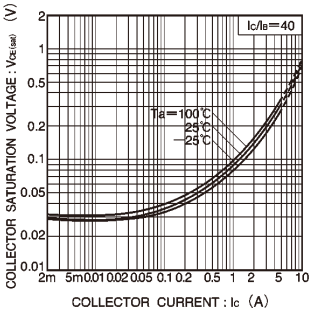


Fig.9 Collector-emitter saturation voltage vs. collector current (Ⅳ)

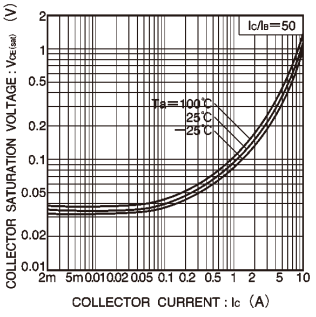


Fig.10 Collector-emitter saturation voltage vs. collector current (Ⅴ)

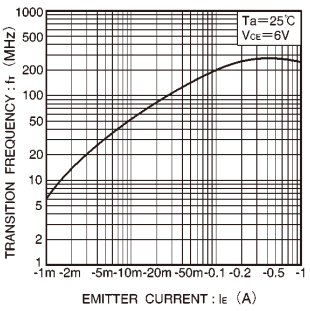


Fig.11 Gain bandwidth product vs. emitter current

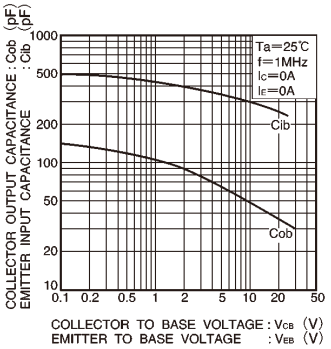


Fig.12 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

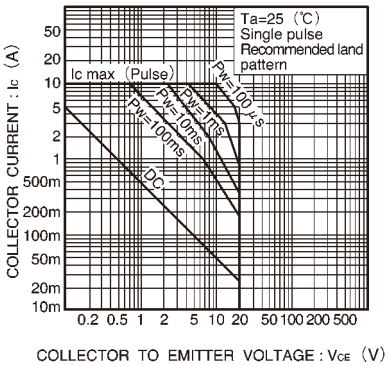


Fig.13 Safe operating area